

## Characterization of Thin Film $\text{CuCr}_2\text{Se}_4$ Synthesized by A Modulated Elemental Reactant Deposition

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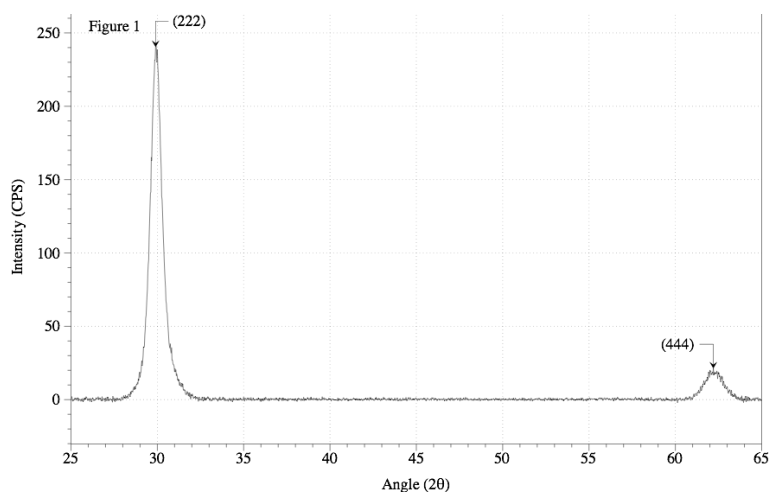
For several decades, spinel-structured compounds of chemical formula  $\text{MCr}_2\text{Se}_4$  (M = first row transition metal) have been of interest for their exceptional intrinsic magnetic properties [1-3]. As opposed to the traditional ferrite spinels, which tend towards ferrimagnetism, these materials typically demonstrate ferromagnetism in addition to magneto-optical and ferroelectric behaviors. An example of particular interest is the compound  $\text{CuCr}_2\text{Se}_4$ , both because of its high Curie temperature and for the changes in magnetization the material undergoes during electromagnetic stimulation. Studies have also suggested that the magnetic properties of these materials are affected by the bulk morphology of the material, with the Curie temperature for nanocrystalline materials differing from those of polycrystalline and thin film materials [3,4]. This work details the XRD, EPMA, and TEM characterization of a  $\text{CuCr}_2\text{Se}_4$  thin film synthesized using a novel single step synthetic method, elucidating a number of previously unexplained aspects of  $\text{CuCr}_2\text{Se}_4$  thin films.

Thin films were deposited by evaporating elemental Cu, Cr, and Se in stoichiometric proportion on wafers of {001} silicon. Films were annealed at 600°C for 1 hour in a nitrogen atmosphere. Samples were initially analyzed using X-ray reflectivity and diffraction. Samples were then cross sectioned and prepared for TEM analysis using the small angle cleavage technique (SACT) [5]. High-resolution (HR) TEM imaging was performed at 300 kV operating voltage with a Philips CM300FEG TEM ( $C_s = 1.2$  mm) using a 10.8 mrad objective aperture semi-angle. Thin-film composition was measured by electron microprobe analysis (EPMA) using a Cameca SX-100 microprobe running Probe for Windows and StrataGem data postprocessing.

The films were found by X-ray diffraction analysis to be single phase and highly textured, as shown in Figure 1. Rocking curves suggest that the film has a preferred growth orientation with the <111> planes parallel to the substrate. EPMA analysis verified the composition of  $\text{CuCr}_2\text{Se}_4$ , as shown in Table 1. HRTEM analysis yielded a lattice image consistent with the spinel structure as shown in Figure 2.

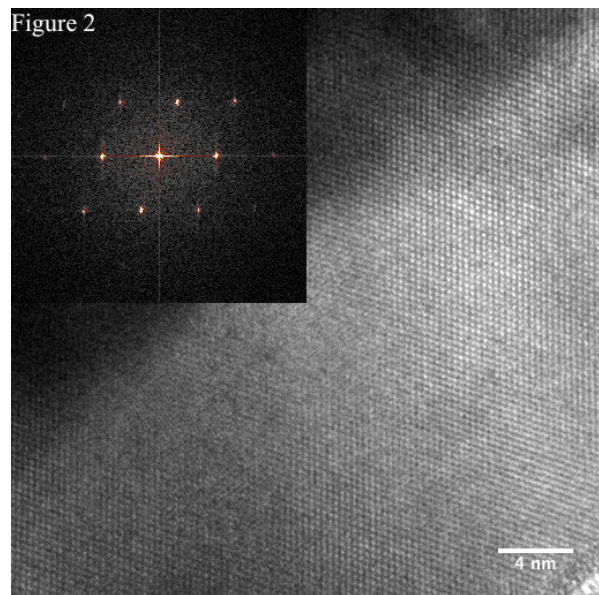
### References

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- [5] J.P. McCaffrey, *Microscopy Research and Technique*. 24 (1993) 180.
- [6] This material is based upon work supported by the University of Oregon's National Science Foundation IGERT Fellowship Program under Grant No. DGE-0549503.



1 reflections

FIG. 1. X-ray diffraction pattern for the thin film  $\text{CuCr}_2\text{Se}_4$  showing an absence of all other reflections except the 222 and 444, suggesting a highly textured film.



$\text{CuCr}_2\text{Se}_4$  thin film viewed

FIG. 2. HRTEM micrograph and (inset) optical diffractogram of the  $\text{CuCr}_2\text{Se}_4$  thin film along the  $[110]$  zone axis.

TABLE 1. EPMA data for  $\text{CuCr}_2\text{Se}_4$  annealed at  $600^\circ\text{C}$  for 1 hour.

Annealing	Cu	Cr	Se
wt%	11.6	21.1	63.3
at%	14.2	28.9	57.0
formula	1	2.04	4.01